

Special Issue

GaN-Based Electronic Materials and Devices

Message from the Guest Editor

This Special Issue will publish research papers and review articles that focus on recent developments in the GaN-based epitaxial layer and GaN-based electronic device technology. The following topics will be explored in this Special Issue: (1) Growth and characterization of GaN-based epitaxial layers. (2) GaN-based power electronics for high-power applications. (3) GaN-based RF HEMT for high-frequency applications. (4) GaN-based 3D nanostructured electronic devices (FinFET, nanowires, and nanosheets). (5) Simulation-based research of GaN HEMT. Welcome to contribute.

Guest Editor

Prof. Dr. Jeong-Gil Kim

Department of Semiconductor, Dong-A University, Busan 49315, Republic of Korea

Deadline for manuscript submissions

closed (15 February 2025)



Electronics

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Impact Factor 2.6
CiteScore 6.1



mdpi.com/si/207082

Electronics
Editorial Office
MDPI, Grosspeteranlage 5
4052 Basel, Switzerland
Tel: +41 61 683 77 34
electronics@mdpi.com

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About the Journal

Message from the Editor-in-Chief

Electronics is a multidisciplinary journal designed to appeal to a diverse audience of research scientists, practitioners, and developers in academia and industry. The journal is devoted to fast publication of latest technological breakthroughs, cutting-edge developments, and timely reviews of current and emerging technologies related to the broad field of electronics. Experimental and theoretical results are published as regular peer-reviewed articles or as articles within Special Issues guest-edited by leading experts in selected topics of interest.

Editor-in-Chief

Prof. Dr. Flavio Canavero

Department of Electronics and Telecommunications, Politecnico di
Torino, 10129 Torino, Italy

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